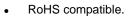
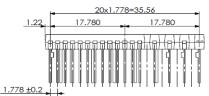
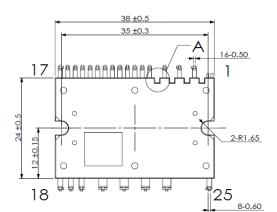
# Compact - IPM ID10FFX60U1S\_D

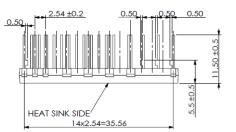
# Features

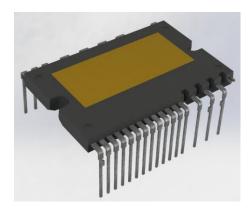
- UL 1557 Certified.
- Adopt the latest trench IGBT technology to get a good overall loss trade-off.
- Open Emitter on N terminal for low cost current sensing application.
- Matched propagation delay and arm shooting through prevention.
- Built-in bootstrap diodes with current limiting resistor.
- Provided a fault signal (FO pin) and shut-off internal IGBT when suffer S.C. and under-voltage faulty event.
- Provided Temperature output by analog signal.

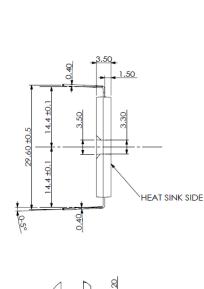








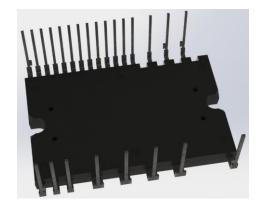




#### **TERMINAL CODE**

| 1 NC                  | 16 COM                    |
|-----------------------|---------------------------|
| 2 V <sub>B(U)</sub>   | <b>17</b> V <sub>от</sub> |
| 3 V <sub>B(V)</sub>   | 18 N <sub>W</sub>         |
| 4 V <sub>B(W)</sub>   | 19 $N_{\rm V}$            |
| 5 IN <sub>(UH)</sub>  | $20 \ N_{\rm U}$          |
| 6 IN <sub>(VH)</sub>  | 21 W                      |
| 7 IN <sub>(WH)</sub>  | 22 V                      |
| $8 V_{CC}$            | 23 U                      |
| 9 COM                 | 24 P                      |
| 10 IN <sub>(UL)</sub> | 25 NC                     |
| 11 $IN_{(VL)}$        |                           |
| 12 IN <sub>(WL)</sub> |                           |
| $13 V_{CC}$           |                           |
| $14 V_{FO}$           |                           |
| $15 C_{SC}$           |                           |

DETAIL A

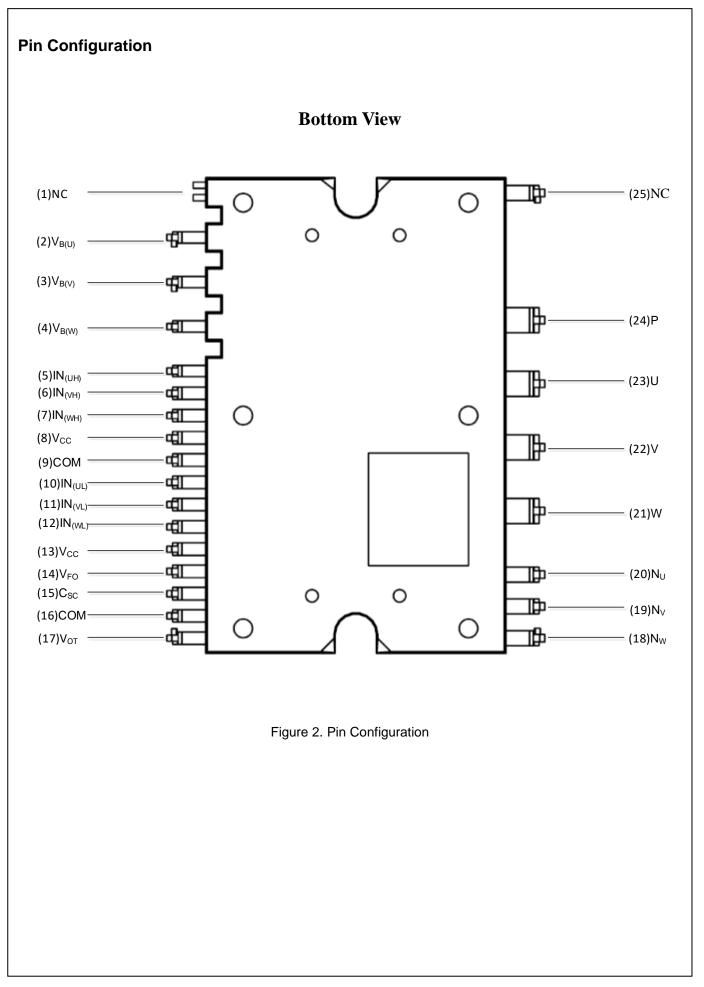


# **Table1: Pin Descriptions**

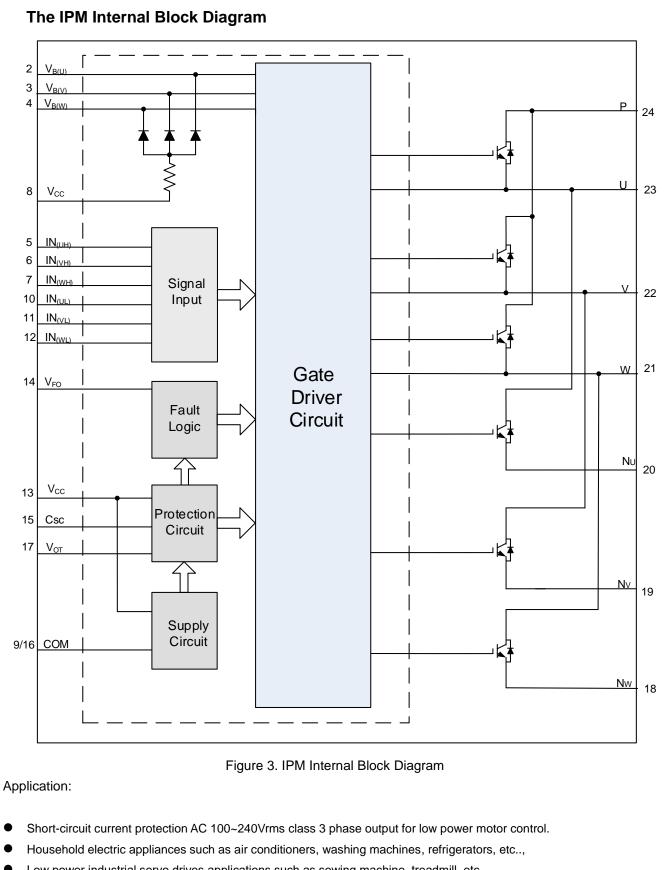
| No. | Symbol             | Pin Description                                   |
|-----|--------------------|---|
| 1   | NC                 | No connection                                     |
| 2   | V <sub>B(U)</sub>  | High - side Bias Voltage for U Phase IGBT Driving |
| 3   | V <sub>B(V)</sub>  | High - side Bias Voltage for V Phase IGBT Driving |
| 4   | V <sub>B(W)</sub>  | High - side Bias Voltage for W Phase IGBT Driving |
| 5   | IN <sub>(UH)</sub> | Signal Input Terminal for High-side U Phase       |
| 6   | IN <sub>(VH)</sub> | Signal Input Terminal for High-side V Phase       |
| 7   | IN <sub>(WH)</sub> | Signal Input Terminal for High-side W Phase       |
| 8   | V <sub>cc</sub>    | Supply Voltage Terminal for Driver IC             |
| 9   | СОМ                | Reference Voltage Terminal for Driver IC          |
| 10  | IN <sub>(UL)</sub> | Signal Input Terminal for Low-side U Phase        |
| 11  | IN <sub>(VL)</sub> | Signal Input Terminal for Low-side V Phase        |
| 12  | IN <sub>(WL)</sub> | Signal Input Terminal for Low-side W Phase        |
| 13  | V <sub>cc</sub>    | Supply Voltage Terminal for Driver IC             |
| 14  | V <sub>FO</sub>    | Fault Output Terminal                             |
| 15  | Csc                | Short-Current Detection Input                     |
| 16  | СОМ                | Reference Voltage Terminal for Driver IC          |
| 17  | V <sub>OT</sub>    | Temperature output                                |
| 18  | Nw                 | Negative DC-Link Input Terminal for W Phase       |
| 19  | Nv                 | Negative DC-Link Input Terminal for V Phase       |
| 20  | Nu                 | Negative DC-Link Input Terminal for U Phase       |
| 21  | W                  | Output Terminal for W Phase                       |
| 22  | V                  | Output Terminal for V Phase                       |
| 23  | U                  | Output Terminal for U Phase                       |
| 24  | Р                  | Positive DC – Link Input                          |
| 25  | NC                 | No connection                                     |

(see figure 2, next page)

# ID10FFX60U1S\_D



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# **MAXIMUM RATINGS** (T<sub>j</sub> = $25^{\circ}$ C)

## **INVERTER PART**

| Item                                 | Symbol                          | Min. | Max. | Unit |
|--------------------------------------|---------------------------------|------|------|------|
| Between collector to emitter voltage | V <sub>CES</sub> (IGBT)         | -    | 600  | V    |
| Supply voltage P-N                   | V <sub>PN</sub>                 | -    | 450  | V    |
| Supply voltage (surge) P-N           | V <sub>PN (surge)</sub>         | -    | 500  | V    |
| Each IGBT collector current          | ± I <sub>C</sub> (Tc = 25℃)     | -    | 10   | А    |
| Each IGBT collector current          | $\pm I_{C}$ (Tc = 90°C)         | -    | 6    | А    |
| Each IGBT collector current (peak)   | $\pm I_{CP}$ (Tc = 25°C, pulse) | -    | 20   | А    |
| Collector dissipation                | $P_C$ (Tc = 25°C, per one chip) | -    | 40   | W    |
| Junction temperature                 | Tj (Note 1)                     | -    | +150 | °C   |

Note 1: Power chip in IPM is qualified for 175°C operation. But overall junction temperature should be limited by  $T_j \leq 125$ °C (@ Tc  $\leq$ 

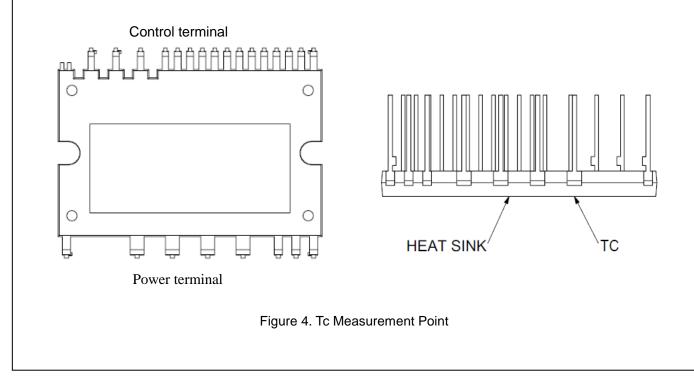
100°C) to fit long term reliability requirement.

### **CONTROL PART**

| Item                             | Symbol  | Min. | Max.    | Unit |
|----------------------------------|---|------|---------|------|
| Driver IC supply voltage         | V <sub>CC</sub>   | -0.3 | 20      | V    |
| P - side floating supply voltage | V <sub>B(u)S(u), B(V)S(V), B(W)S(W)</sub>                               | -0.3 | 20      | V    |
| Current sensing input voltage    | V <sub>SC</sub>   | -0.3 | Vcc+0.3 | V    |
| Logic input voltage              | $IN_{(UH)}, IN_{(VH)}, IN_{(WH)},$<br>$IN_{(UL)}, IN_{(VL)}, IN_{(WL)}$ | -0.3 | Vcc+0.3 | V    |
| Fault output voltage             | V <sub>FO</sub>   | -0.3 | Vcc+0.3 | V    |
| Fault output current             | I <sub>FO</sub>   | -    | 1       | mA   |

# TOTAL SYSTEM

| Item  | Symbol           | Min. | Max. | Unit |
|---|------------------|------|------|------|
| Module case operating temperature   | T <sub>c</sub>   | -20  | +100 | °C   |
| Storage temperature   | T <sub>stg</sub> | -40  | +125 | °C   |
| Isolation voltage (60Hz Sinusoidal, AC 1 minute, pins to heat-sink plate) | V <sub>iso</sub> | -    | 1500 | Vrms |



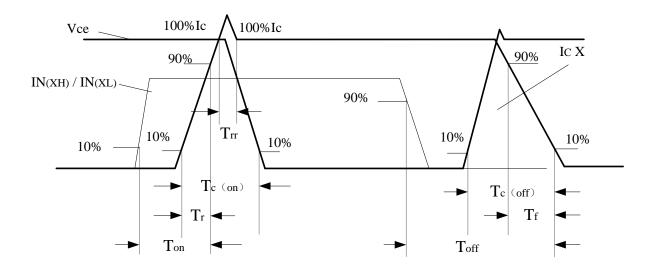
## THERMAL RESISTANCE

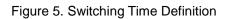
| Item                     | Symbol                | Condition       | Min. | Тур. | Max. | Unit |
|--------------------------|-----------------------|-----------------|------|------|------|------|
| Junction to case thermal | R <sub>th(j-c)Q</sub> | IGBT part (1/6) | -    | 3.0  | -    | °C∕W |
| resistance               | R <sub>th(j-c)F</sub> | FWD part (1/6)  | -    | 2.7  | -    | C/VV |

ELECTRICAL CHARACTERISTICS (Tj = 25 °C)

#### **INVERTER PART**

| Item                                 | Symbol                | Condition   | Min. | Тур. | Max. | Unit |
|--------------------------------------|-----------------------|---|------|------|------|------|
| Collector-emitter saturation voltage | V <sub>CE (sat)</sub> | $ \begin{array}{ccc} V_{CC} = & V_{B(U)S(U), \ B(V)S(V), \ B(W)S(W)} = \\ 15V, \ I_{C} = & 10A, \ V_{SC} = & 0V \end{array} \end{array} \  \  T_{j} = & 25 \ {}^{\circ} {\mathbb C} \end{array} $ | -    | 1.50 | -    | V    |
| FWD forward voltage drop             | VF                    | T <sub>j</sub> =25°C, - I <sub>C</sub> = 10A  | -    | 1.40 | -    | V    |
|                                      | $T_{on}$              | V <sub>D</sub> = 300V,  | -    | 0.85 | -    |      |
|                                      | T <sub>c(on)</sub>    | $V_{CC} = V_{B(U), B(V), B(W)} = 15V,$  | -    | 0.25 | -    |      |
| Switching times<br>(Fig. 5)          | $T_{off}$             | $I_{C} = 10A, T_{j} = 25^{\circ}C,$   | -    | 0.90 | -    | μS   |
| (19.3)                               | $T_{c(off)}$          | V <sub>IN</sub> = 5V <> 0V,   | •    | 0.10 | -    |      |
|                                      | T <sub>rr</sub>       | $V_{SC} = 0V$ , Inductive Load  | -    | 0.15 | -    |      |
| Collector-emitter cut-off<br>current | I <sub>CES</sub>      | V <sub>CE</sub> =V <sub>CES</sub>   | -    | -    | 500  | μA   |

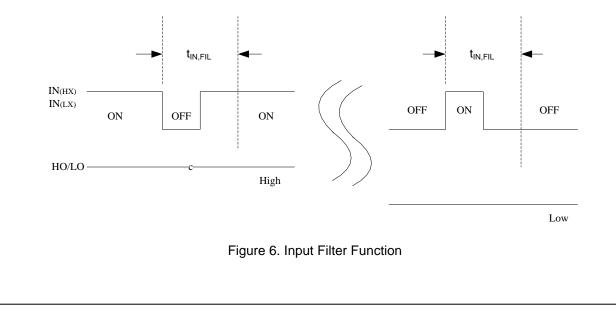


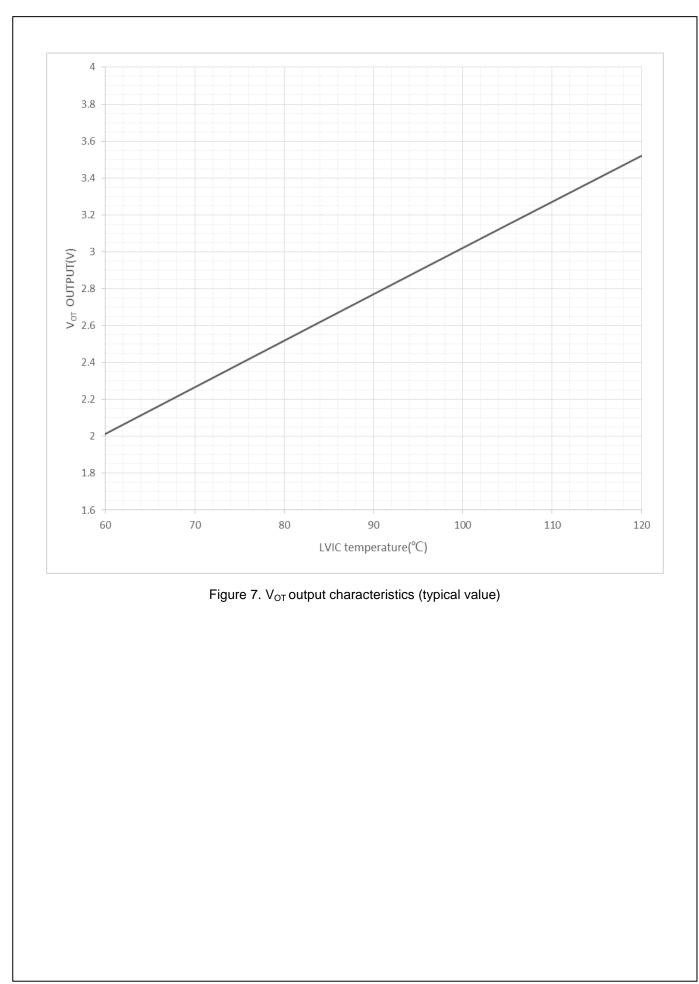


| Item  | Symbol  | Condition   | Min.  | Тур.     | Max.  | Unit |
|---|---|---|-------|----------|-------|------|
| IN <sub>(UH、VH、WH)</sub> , IN <sub>(UL、VL、WL)</sub><br>ON threshold voltage | V <sub>th(on)</sub>                                   |   | -     | 2.0      | 2.4   | V    |
| IN <sub>(UH、VH、WH)</sub> ,IN <sub>(UL、VL、WL)</sub><br>OFF threshold voltage | V <sub>th(off)</sub>                                  |   | 0.8   | 1.1      | -     | V    |
| IN <sub>(UH、VH、WH)</sub> input bias current                                 |   | $V_{IN(UH, VH, WH)} = 5V$ $V_{IN(UH, VH, WH)} = 0V$   | 0.7   | 1.0<br>0 | 1.5   | mA   |
|   | IIN(UH、VH、WH) (LO)<br>IIN(UL、VL、WL) (HI)              | $V_{\text{IN}(\text{UL}, \text{VL}, \text{WL})} = 5V$ | 0.7-  | 1.0      | 1.3   |      |
| $IN_{(UL, VL, WL)}$ input bias current                                      | IN(UL, VL, WL) (LO)                                   | $V_{\text{IN}(\text{UL}, \text{VL}, \text{WL})} = 0V$ | -     | 0        | -     | mA   |
| Driver IC supply voltage  | Vcc   | X   | 13.5  | 15.0     | 16.5  | V    |
| P - side floating supply voltage  | V <sub>B(U)</sub> , <sub>B(V)</sub> , <sub>B(W)</sub> |   | 13.5  | 15.0     | 16.5  | V    |
| V <sub>CC</sub> terminal input current                                      | lc  |   | -     | -        | 2.3   | mA   |
|   | V <sub>FOH</sub>                                      | V <sub>SC</sub> =0V (Note 2)                          | 4.9   | -        | -     | V    |
| Fault output voltage  | V <sub>FOL</sub>                                      | V <sub>SC</sub> =1V                                   | -     | -        | 950   | mV   |
| Short circuit trip level  | V <sub>SC(ref)</sub>                                  | $V_{CC} = 15V, T_j = 25^{\circ}C$                     | 0.455 | 0.480    | 0.505 | V    |
| Fault output pulse width  | t <sub>FOD</sub>                                      |   | 20    | 65       | -     | us   |
| N-side Supply circuit under voltage   | UVT <sub>VCC</sub>                                    | Trip level  | 9.5   | 10.4     | 11.0  | V    |
| protection  | UVR <sub>VCC</sub>                                    | Reset level   | 11.0  | 12.0     | 12.8  | V    |
| protection  | UVH   | Hysteresis  | -     | 1.6      | -     | V    |
| P-side Supply circuit under voltage   | UVT <sub>Vb</sub>                                     | Trip level  | 9.5   | 10.4     | 11.0  | V    |
| protection  | UVR <sub>Vb</sub>                                     | Reset level   | 11.0  | 12.0     | 12.8  | V    |
| protection  | UVH   | Hysteresis  | -     | 1.6      | -     | V    |
| $IN_{(UL,\ VL,\ WL)}$ Input filter time                                     | t <sub>IN,FIL</sub>                                   | VIN = 0 & 5V (Note 3)                                 | 100   | 200      | -     | ns   |
| Temperature Output  | V <sub>OT</sub>                                       | LVIC temperature=90°C                                 | -     | 2.77     | -     | V    |
|   | ¥01   | LVIC temperature=25℃                                  | -     | 1.13     | -     | V    |
| VF  | Bootstrap diode<br>forward voltage                    | If=10mA, $T_j$ = 25 $^\circ C$                        | 0.8   | -        | 1.1   | V    |
| R   | Limiting resistance                                   | Individual resistor                                   | -     | 25       | -     | Ohm  |

**Note 2:**  $V_{FO}$  output is open collector type, so this signal line should be pulled up to the +5V power supply with approximately 4.7K $\Omega$ **Note 3:** For high side PWM, IN(UH, VH, WH) pulse width must be  $\geq$  1 us.

# **Input Filter Function**





# **RECOMMENDED OPERATION CONDITIONS**

| Item                             | Symbol                         | Condition   | Min.      | Тур. | Max. | Unit |
|----------------------------------|--------------------------------|---|-----------|------|------|------|
| DC – Link Supply voltage         | VD                             | Applied between P-N                                 | 0         | 400  | 450  | V    |
| Driver IC supply voltage         | V <sub>CC</sub>                | Applied between V <sub>CC</sub> - COM               | 13.5      | 15.0 | 16.5 | V    |
| P - side floating supply voltage | V <sub>BS</sub>                | Applied between $V_{B(u,\ v,\ w)}-V_{S(u,\ v,\ w)}$ | 13.5      | 15.0 | 16.5 | V    |
| Input ON threshold voltage       | V <sub>sc(ON)</sub>            | Applied between IN(UH, VH, WH) - COM                | 0 ~ 0.65  |      | V    |      |
| Input OFF threshold voltage      | $V_{sc(OFF)}$                  | and IN <sub>(UL、VL、WL)</sub> - COM                  | 4.0 ~ 5.5 |      | V    |      |
| Supply voltage ripple            | $\Delta V_D$ , $\Delta V_{DB}$ |   | -1        | -    | 1    | V/µs |
| Arm shoot-through blocking time  | t <sub>dead</sub>              |   | 1         | -    | -    | μs   |
| PWM input frequency              | f <sub>PWM</sub>               | T <sub>C</sub> ≦100℃, T <sub>j</sub> ≦125℃          | -         | 15   | -    | kHz  |

# MECHANICAL CHARACTERISTICS AND RATINGS

| Item               | Condition             |                     |      | Тур. | Max. | Unit |
|--------------------|-----------------------|---------------------|------|------|------|------|
| Mounting torque    | Mounting<br>screw: M3 | Recommended 0.65N•m | 0.60 | 0.65 | 0.70 | N•m  |
| Weight             |                       |                     | -    | 9.5  | -    | g    |
| Heat-sink flatness |                       |                     | -50  | -    | 100  | μm   |

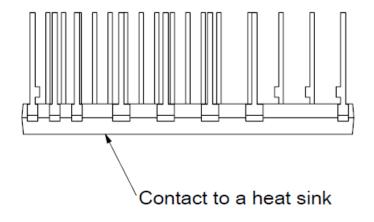
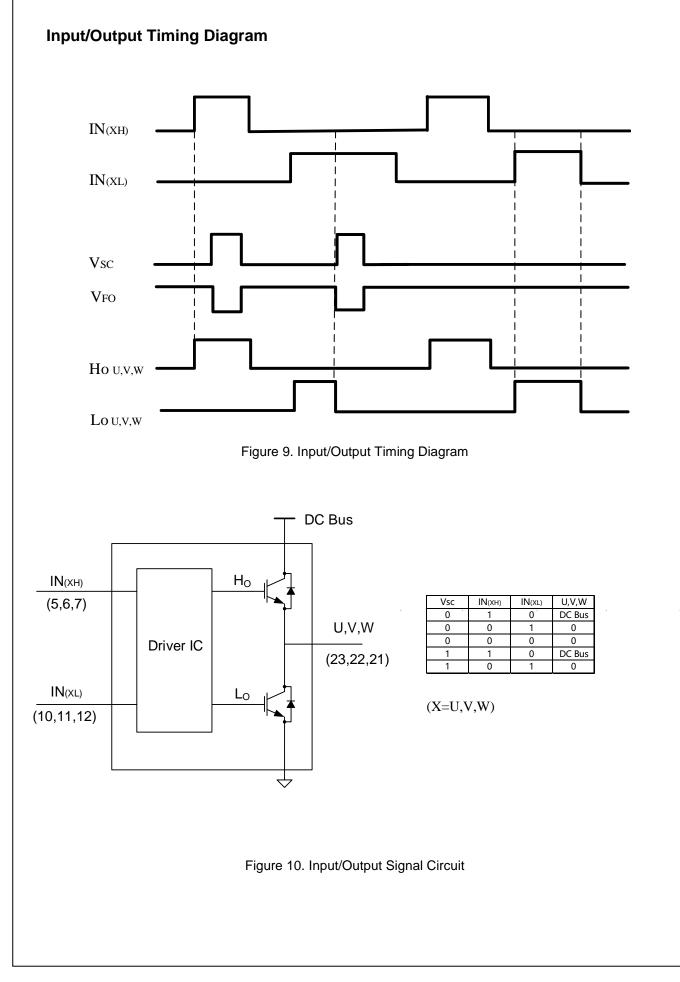
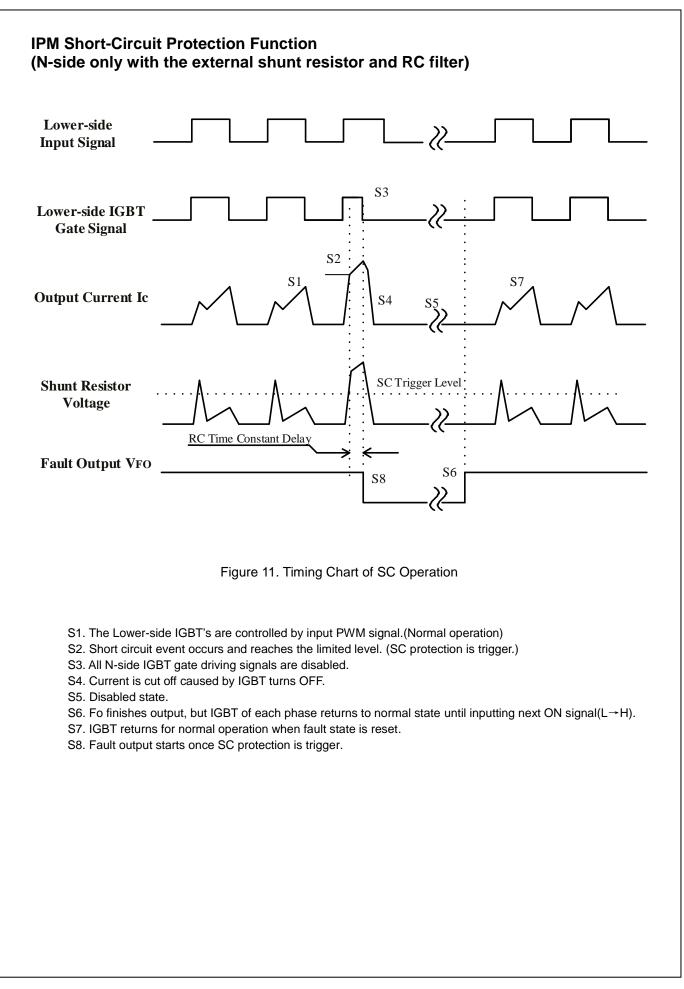
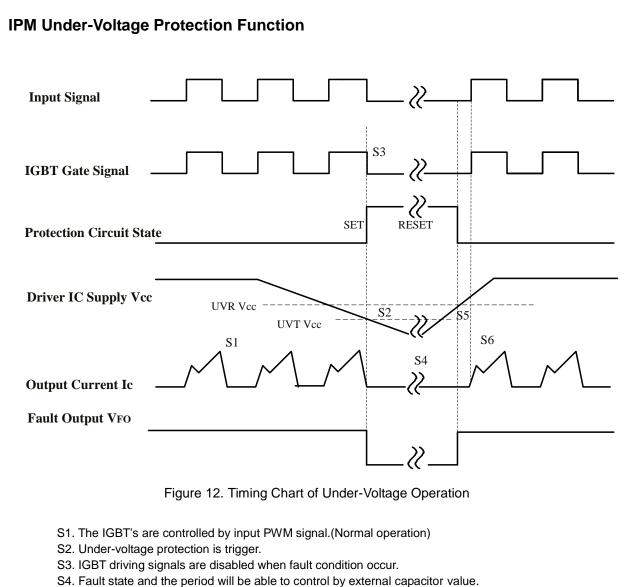


Figure 8. Measurement Location of Heat-sink Flatness

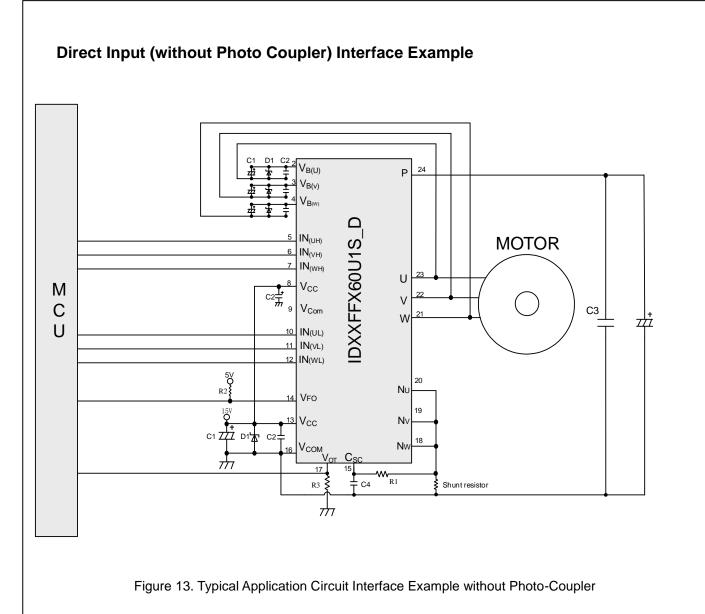


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- S5. Under-voltage event is recovered.
- S6. IGBT returns for normal operation when fault state is reset.



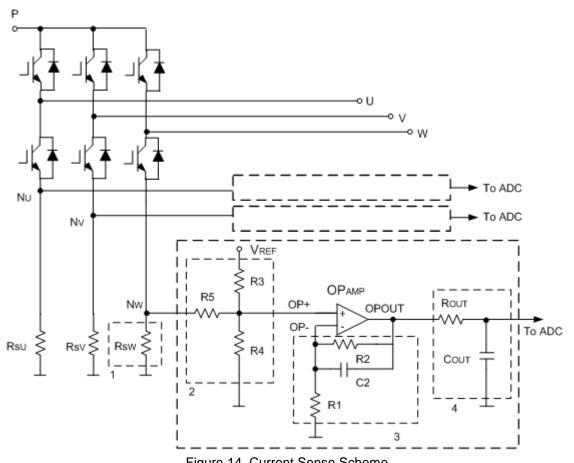
#### Design reference:

- $1. \quad R1:100\Omega$
- 2. R2 :  $4.7K\Omega$  (VFO output is open collector so to have a pull high resistor is needed. )

3. R3 : 5k-200k pull down resistor for getting linear output characteristics at low temperature below room temperature.

- 4. C1 : 10 ~ 100 $\mu$ F ( Electrolytic, low impendence )
- 5. C2: 100 ~ 1000pF (Ceramic) (The capacitor could filter the noise, but should be careful to the dead time)
- 6. C3 : 220 $\mu$ F (Electrolytic, low impendence )
- 7. D1 : Zener diode (It is recommended to insert a Zener diode to prevent gate lifting and surge destruction)
- 8. Only connect either pin 9 or pin 16 to ground, do not connect both together to form the ground loop internally.

#### **Current Sense Shceme**



#### Figure 14. Current Sense Scheme

#### Description:

- 1、Half-bridge current sensing
- $2 \ensuremath{\,{\ensuremath{\scriptscriptstyle S}}}$  Voltage shifting of the  $V_{\text{sense}}$
- 3、Voltage gain and filtering
- $4 \searrow$  Capacitor required by the ADC for sampling purpose

R<sub>OUT</sub> resistor is usually required in order to make the OP<sub>AMP</sub> stable when the C<sub>OUT</sub> capacitance increases

#### Design Reference:

- 1. R1 : 1.0 KΩ
- 2. R2 : 5.6 KΩ
- 3. R3 : 4.7 KΩ
- 4. R4: 910 Ω
- 5. R5 : 910  $\Omega$
- 6. ROUT : 1.0 KΩ
- 7. C2 :10pF ( Ceramic )

# **Precautions on Electrostatic Electricity**

- (1) Operators must wear anti-static clothing and conductive shoes (or a leg or heel strap).
- (2) Operators must wear a wrist strap grounded to earth via a resistor of about 1 M $\Omega$ .
- (3) Soldering irons must be grounded from iron tip to earth, and must be used only at low voltages.
- (4) If the tweezers you use are likely to touch the device terminals, use anti-static tweezers and in particular avoid metallic tweezers. If a charged device touches a low-resistance tool, rapid discharge can occur. When using vacuum tweezers, attach a conductive chucking pat to the tip, and connect it to a dedicated ground used especially for anti-static purposes (suggested resistance value: 10<sup>4</sup> to 10<sup>8</sup>Ω).
- (5) Do not place devices or their containers near sources of strong electrical fields (such as above a CRT).
- (6) When storing printed circuit boards which have devices mounted on them, use a board container or bag that's protected against static charge. To avoid the occurrence of static charge or discharge due to friction, keep the boards separate from one other and do not stack them directly on top of one another.
- (7) Ensure, if possible, that any articles (such as clipboards) which are brought to any location where the level of static electricity must be closely controlled are constructed of anti-static materials.
- (8) In cases where the human body comes into direct contact with a device, be sure to wear anti-static finger covers or gloves (suggested resistance value: 10<sup>8</sup>Ω or less).
- (9) Equipment safety covers installed near devices should have resistance ratings of  $10^9\Omega$  or less.
- (10) If a wrist strap cannot be used for some reason, and there is a possibility of imparting friction to devices, use an ionizer.

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